

March 2011

# MPSA06 / MMBTA06 / PZTA06 NPN General Purpose Amplifier

## **Features**

- This device is designed for general purpose amplifer applications at collector currents to 300mA.
- Sourced from Process 33.



# **Absolute Maximum Ratings \*** T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	80	V
V <sub>CBO</sub>	Collector-Base Voltage	80	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
I <sub>C</sub>	Collector Current - Continuous	500	mA
T <sub>J,</sub> T <sub>stg</sub>	Operating and Storage Junction Temperature Range	- 55 to +150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# **Thermal Characteristics** $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.			Units
		MPSA06	*MMBTA06	**PZTA06	Office
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	1,000 8.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

<sup>\*</sup> Device mounted on FR-4 PCB 1.6"  $\times$  1.6"  $\times$  0.06".

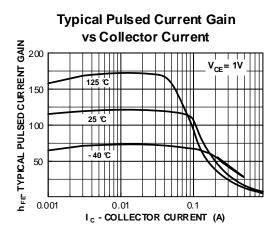
<sup>\*\*</sup> Device mounted on FR-4 PCB 36mm × 18mm × 1.5mm; mounting pad for the collector lead min. 6cm<sup>2</sup>.

# **Electrical Characteristics** $T_a = 25\%$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units	
Off Characteri	Off Characteristics					
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage*	$I_C = 1.0 \text{mA}, I_B = 0$	80		V	
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 100 \mu A, I_C = 0$	4.0		V	
I <sub>CEO</sub>	Collector-Cutoff Current	$V_{CE} = 60V, I_{B} = 0$		0.1	μΑ	
I <sub>CBO</sub>	Collector-Cutoff Current	$V_{CB} = 80V, I_{E} = 0$		0.1	μΑ	
On Characteri	On Characteristics					
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 1.0V I <sub>C</sub> = 100mA, V <sub>CE</sub> = 1.0V	100 100			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 100mA, I <sub>B</sub> = 10mA		0.25	V	
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 1.0V		1.2	V	
Small Signal Characteristics						
f <sub>T</sub>	Current Gain - Bandwidth Product	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 2.0V, f = 100MHz	100		MHz	

<sup>\*</sup> Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

# **Typical Performance Characteristics**



**Figure 1. Typical Pulsed Current Gain** vs Collector Current

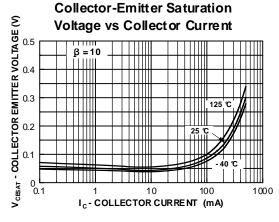


Figure 2. Collector-Emitter Saturation Voltage vs Collector Current

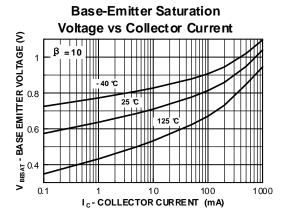


Figure 3. Base-Emitter Saturation Voltage vs Collector Current

Collector-Cutoff Current

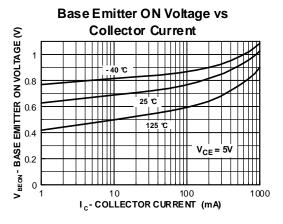
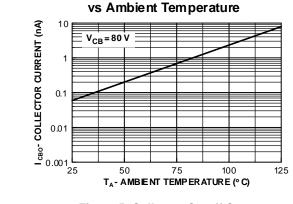


Figure 4. Base-Emitter On Voltage vs Collector Current



**Figure 5. Collector Cutoff Current** vs Ambient Temperature

T<sub>A</sub> - AMBIENT TEMPERATURE (°C)

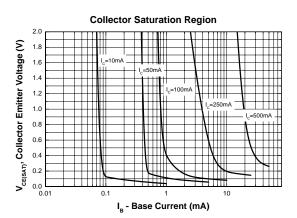


Figure 6. Collector Saturation Region

125

# Typical Performance Characteristics (continued)

**Collector-Emitter Breakdown** 

# Voltage with Resistance **Between Emitter-Base**

0.1

Figure 7. Collector-Emitter Breakdown Voltage with Resistance Between Emitter-Base

RESISTANCE  $(k\Omega)$ 

100

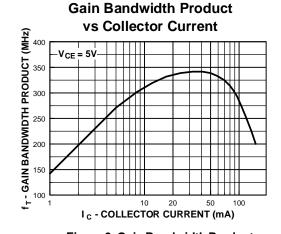


Figure 9. Gain Bandwidth Product vs Collector Current

# **Input and Output Capacitance** vs Reverse Voltage

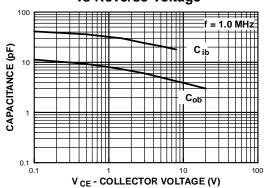


Figure 8. Input and Output Capacitance vs Reverse Voltage

## **Power Dissipation vs Ambient Temperature**

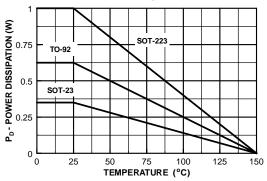


Figure 10. Power Dissipation vs **Ambient Temperature** 





#### TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

 Build it Now™
 Green FPS™

 CorePLUS™
 Green FPS™ e-Series™

 CorePOWFR™
 Gmax™

GTO™

IntelliMAX™

MegaBuck™

MicroFFT™

MicroPak™

MicroPak2™

MillerDrive™

MotionMax™

mWSaver™

OptoHiT™

Motion-SPM™

OPTOLOGIC®

OPTOPLANAR®

ISOPLANAR™

MICROCOUPLER™

CorePOWER™

CROSSVOLT™

CTL™

Current Transfer Logic™

DEUXPEED®
Dual Cool<sup>TM</sup>
EcoSPARK®
EfficientMax<sup>TM</sup>
ESBC<sup>TM</sup>

Fairchild®
Fairchild Semiconductor®
FACT Quiet Series™

FACT<sup>®</sup>
FAST<sup>®</sup>
FastvCore<sup>™</sup>
FETBench<sup>™</sup>
FlashWriter<sup>®\*</sup>

FlashWriter<sup>®</sup>\* FPS™

PDP SPM PDP SPM

Power-SPM™ PowerTrench® PowerXS™

**QFET** 

Programmable Active Droop™

QS™ Quiet Series™ RapidConfigure™

Saving our world, 1mW/W/kW at a time™

ER™ SignalWise™
SmartMax™
SMART START™
SPM®
STEALTH™
SuperFET®

SuperFET®
SuperSOT™-3
SuperSOT™-6
SuperSOT™-8
SuperSOT™-8
SupreMOS®
SyncFET™
Sync-Lock™

SYSTEM ®\*

The Power Franchise®

The Right Technology for Your Success™

franchise
TinyBoost™
TinyBuck™
TinyCalc™
TinyCoptc®
TinyPoptco™
TinyPower™
TinyPower™
TinyPower™

TinyWire™
TriFault Detect™
TRUECURRENT®\*
μSerDes™

SerDes WHC
Ultra FRFET™
VCX™
VisualMax™
XS™

\* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

#### As used herein:

- Life support devices or systems are devices or systems which, (a)
  are intended for surgical implant into the body or (b) support or
  sustain life, and (c) whose failure to perform when properly used in
  accordance with instructions for use provided in the labeling, can be
  reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### PRODUCT STATUS DEFINITIONS

### **Definition of Terms**

Definition of Terms				
Datasheet Identification	Product Status	Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

Rev. I53